Registration No :		
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Total Number of Pages: 01

M.Sc.I FCYF605

6th Semester Regular/Back Examination 2018–19 SOLID STATE CHEMISTRY BRANCH : M.Sc.I(AC)

Time: 3 Hours
Max Marks: 70
Q.CODE: F546

Answer Question No.1, which is compulsory, and any FIVE from the rest.

The figures in the right hand margin indicate marks.

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Q1	a) b) c) d) e) f) g) h) i)	Answer the following questions: The cubic closepacked structure is based on an FCC unit cell. Explain it. Briefly discuss the triclinic and monoclinic crystal systems with examples. Calculate the number of atoms per unit cell of hexagonal lattice cell. State the critical phenomena of solids. Explain martensite-austenite phase transitions. What do you mean by optical band gap? What do you mean by tailoring of solids? State superconductivity in solids. What is the difference between four-probe and two-probe measurement method for electrical resistivity? Why SQUID-VSM Magnetometer is suitable to measure magnetic properties of solids.	(2 x 10)
Q2	a) b)	Discusspacking in solidsin details. Molybdenum (atomic mass = 95.94) has a density of 10.2 gm/cm³ and lattice parameter of 3.15 Å. Find the number of atoms per unit cell and predict the type of crystal structure. Derive expression for Born-Landé equation for the lattice energy of an ionic crystal.	(5) (5)
Q3	a) b)	Explain stereographic projections in crystallography using suitable examples. Discuss the crystal structures of silicates.	(5) (5)
Q4	a) b)	Describe different defects with schematic diagrams. Describe diffusion mechanisms in solids.	(5) (5)
Q5	a) b)	Discuss the methods for single crystal growth and thin films depositions. Discuss spectroscopic characterization techniques (Mossbauer, IR, and UV-Vis) for solids.	(5) (5)
Q6	a)	Explain bonding in solids based on band theory of solids.	(10)
Q7	a)	Describe electron microscopic (SEM, TEM, and AFM) characterization techniques for solids.	(10)
Q8	a) b)	Write short answer on any TWO: Color centres. Powder processing	(5 x 2)

c) Structure-property relations.